

R-C Thermal Model Parameters

DESCRIPTION

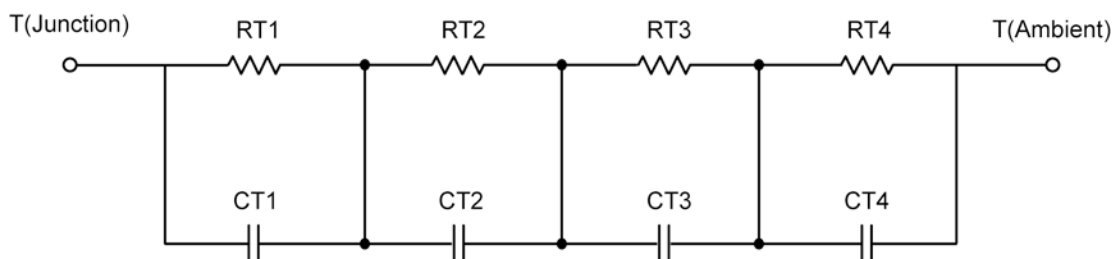
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



| R-C VALUES FOR TANK CONFIGURATION | | | |
|------------------------------------------|------------|------|------|
| Thermal Resistance (°C/W) | | | |
| Junction to | Ambient | Case | Foot |
| RT1 | 219.6709 | N/A | N/A |
| RT2 | 48.4012 | N/A | N/A |
| RT3 | 151.3088 | N/A | N/A |
| RT4 | 230.6191 | N/A | N/A |
| Thermal Capacitance (Joules/°C) | | | |
| Junction to | Ambient | Case | Foot |
| CT1 | 49.0316 m | N/A | N/A |
| CT2 | 15.0301 m | N/A | N/A |
| CT3 | 777.0842 m | N/A | N/A |
| CT4 | 29.6834 m | N/A | N/A |

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

| Thermal Resistance ($^{\circ}\text{C}/\text{W}$) | | | |
|----------------------------------------------------|------------|------|------|
| Junction to | Ambient | Case | Foot |
| RF1 | 99.5138 | N/A | N/A |
| RF2 | 220.7992 | N/A | N/A |
| RF3 | 189.5926 | N/A | N/A |
| RF4 | 140.0944 | N/A | N/A |
| Thermal Capacitance (Joules/ $^{\circ}\text{C}$) | | | |
| Junction to | Ambient | Case | Foot |
| CF1 | 7.0154 m | N/A | N/A |
| CF2 | 11.0921 m | N/A | N/A |
| CF3 | 2.8720 m | N/A | N/A |
| CF4 | 765.2724 m | N/A | N/A |

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002

